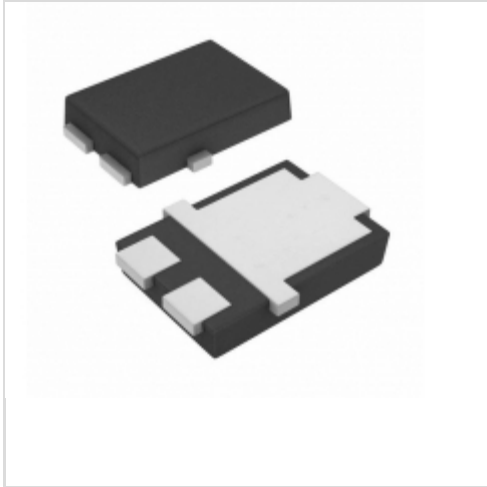


AS3PK-M3/87A



Vishay / Semiconductor - Diodes Division

DIODE AVALANCHE 800V 2.1A TO277A

Lead free / RoHS Compliant

Discrete Semiconductor Products

[AS3PK-M3/87A.pdf](#)

[Buy Now](#)

Out Stock

0 pcs

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

We can supply AS3PK-M3/87A, use the request quote form to request AS3PK-M3/87A price and lead time. Zeano is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number AS3PK-M3/87A. The price and lead time for AS3PK-M3/87A depending on the quantity required and warehouse location. Contact us and our sales representative will provide you price. We look forward to work with you.

Shopping Process

1

Confirm the product

2

submit the order

3

payment

4

wait for delivery

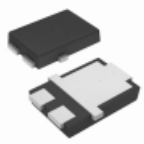
5

receive the goods

Specifications

Voltage - Forward (Vf) (Max) @ If:	920mV @ 1.5A
Voltage - DC Reverse (Vr) (Max):	800V
Supplier Device Package:	TO-277A (SMPC)
Speed:	Standard Recovery >500ns, > 200mA (Io)
Series:	eSMP®
Reverse Recovery Time (trr):	1.2µs
Packaging:	Tape & Reel (TR)
Package / Case:	TO-277, 3-PowerDFN
Operating Temperature - Junction:	-55°C ~ 175°C
Mounting Type:	Surface Mount
Diode Type:	Avalanche
Current - Reverse Leakage @ Vr:	10µA @ 800V
Current - Average Rectified (Io):	2.1A (DC)
Capacitance @ Vr, F:	37pF @ 4V, 1MHz

Related products

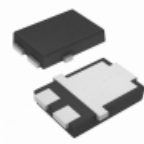


AS3PJHM3_A/H

DIODE AVALANCHE 600V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

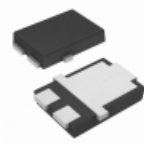


AS3PJHM3/86A

DIODE AVALANCHE 600V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

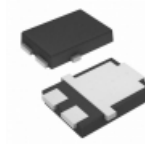


AS3PKHM3_A/I

DIODE AVALANCHE 800V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

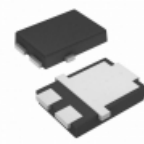


AS3PM-M3/86A

DIODE AVALANCHE 1KV 2.1A TO277

[Vishay Semiconductor Diodes Division](#)

RFQ



AS3PK-M3/86A

DIODE AVALANCHE 800V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

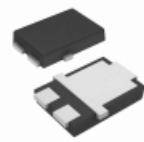


AS3PKHM3/86A

DIODE AVALANCHE 800V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

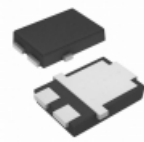


AS3PKHM3/87A

DIODE AVALANCHE 800V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

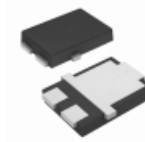


AS3PJHM3/87A

DIODE AVALANCHE 600V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

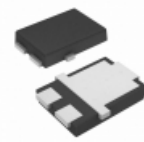


AS3PJHM3_A/I

DIODE AVALANCHE 600V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ



AS3PKHM3_A/H

DIODE AVALANCHE 800V 2.1A TO277A

[Vishay Semiconductor Diodes Division](#)

RFQ

Guess You May Looking For

SiTime

SIT8008AC-13-33S-30.000000D

OSC MEMS 30.0000MHZ LVCMOS SMD

[SITIME](#)

RFQ



SIT1602BC-83-30E-72.000000Y

-20 TO 70C, 7050, 50PPM, 3.0V, 7

[SITIME](#)

RFQ

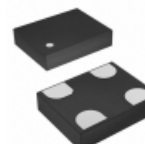


SIT1602BI-33-18N-72.000000Y

-40 TO 85C, 5032, 50PPM, 1.8V, 7

[SITIME](#)

RFQ



SIT1602BC-22-XXE-14.000000D

-20 TO 70C, 3225, 25PPM, 2.25V-3

[SITIME](#)

RFQ



SIT1602BI-71-33N-66.666000D

-40 TO 85C, 2016, 20PPM, 3.3V, 6

[SITIME](#)

RFQ



SIT8008BC-71-33S-4.000000D

OSC MEMS 4.0000MHZ LVCMOS SMD

[SITIME](#)

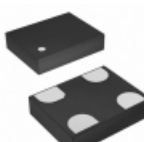
RFQ



SIT8008BC-33-18E-33.3333333Y

OSC MEMS 33.3333333MHZ LVCMOS SMD

RFQ



SIT1602BI-22-30E-10.000000D

-40 TO 85C, 3225, 25PPM, 3.0V, 1

[SITIME](#)

RFQ

SiTime

SIT8008AC-11-33E-13.000000D

OSC MEMS 13.0000MHZ LVCMOS SMD

[SITIME](#)

RFQ



SIT1602BI-81-18N-37.500000Y

-40 TO 85C, 7050, 20PPM, 1.8V, 3

[SITIME](#)

RFQ